Ultra-Low Capacitance ESD Protection

Micro-Packaged Diodes for ESD Protection

The ESD8472MUT5G is designed to protect voltage sensitive components that require ultra-low capacitance from ESD and transient voltage events. Excellent clamping capability, low capacitance, high breakdown voltage, high linearity, low leakage, and fast response time make these parts ideal for ESD protection on designs where board space is at a premium. It has industry leading capacitance linearity over voltage making it ideal for RF applications. This capacitance linearity combined with the extremely small package and low insertion loss makes this part well suited for use in antenna line applications for wireless handsets and terminals.

Features

- Industry Leading Capacitance Linearity Over Voltage
- Ultra-Low Capacitance: 0.2 pF
- Insertion Loss: 0.030 dBm
- 0201DNS Package: 0.60 mm x 0.30 mm
- Stand-off Voltage: 5.3 V
- Low Leakage: < 1 nA
- Low Dynamic Resistance: $< 1 \Omega$
- IEC61000-4-2 Level 4 ESD Protection
- 1000 ESD IEC61000-4-2 Strikes ±8 kV Contact / Air Discharged
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- RF Signal ESD Protection
- RF Switching, PA, and Antenna ESD Protection
- Near Field Communications
- USB 2.0, USB 3.0

© Semiconductor Components Indu

October, 2012 - Rev.

MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
IEC 61000-4-2 (ESD) (Note 1)		20	kV
IEC 61000-4-5 (ESD) (Note 2)		3.0	А
Total Power Dissipation (Note 3) @ T _A = 25°C Thermal Resistance, Junction-to-Ambient	$P_D \\ R_{\theta J A}$	300 400	mW °C/W
Junction and Storage Temperature Range	T _J , T _{stg}	–55 to +150	°C
Lead Solder Temperature – Maximum (10 Second Duration)	ΤL	260	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- 1. Non-repetitive current pulse at $T_A = 25^{\circ}C$, per IEC61000-4-2 waveform.
- 2. Non-repetitive current pulse at T_A = 25°C, per IEC61000-4-5 waveform.

W.BDTIC.com/C

3. Mounted with recommended minimum pad size, DC board FR-4



ON Semiconductor®

http://onsemi.com





4 = Specific Device Code

M = Date Code

ORDERING INFORMATION

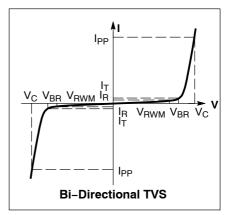
Device	Package	Shipping [†]
ESD8472MUT5G	X3DFN2 (Pb-Free)	15000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS

(T_A = 25°C unless otherwise noted)

Symbol	Parameter
I _{PP}	Maximum Reverse Peak Pulse Current
V _C	Clamping Voltage @ I _{PP}
V _{RWM}	Working Peak Reverse Voltage
I _R	Maximum Reverse Leakage Current @ V _{RWM}
V _{BR}	Breakdown Voltage @ I _T
Ι _Τ	Test Current

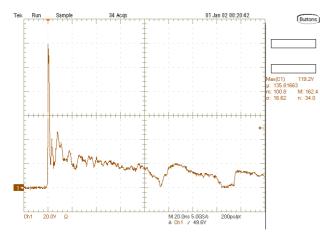


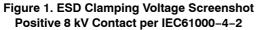
*See Application Note AND8308/D for detailed explanations of datasheet parameters.

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Reverse Working Voltage	V _{RWM}				5.3	V
Breakdown Voltage	V _{BR}	I _T = 1 mA (Note 4)	7.0			V
Reverse Leakage Current	I _R	V _{RWM} = 5.3 V		< 1	50	nA
Clamping Voltage	V _C	I _{PP} = 1 A (Note 5)		11	15	V
Clamping Voltage	V _C	I _{PP} = 3 A (Note 5)		14	20	V
ESD Clamping Voltage	V _C	Per IEC61000-4-2	See	See Figures 1 and 2		
Junction Capacitance	CJ	$V_R = 0 V$, f = 1 MHz $V_R = 0 V$, f = 1 GHz		0.20 0.15	0.30 0.30	pF
Dynamic Resistance	R _{DYN}	TLP Pulse		1		Ω
Insertion Loss		f = 1 MHz f = 8.5 GHz		0.050 0.250		dB

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Breakdown voltage is tested from pin 1 to 2 and pin 2 to 1.
Non-repetitive current pulse at 25°C, per IEC61000-4-5 waveform.





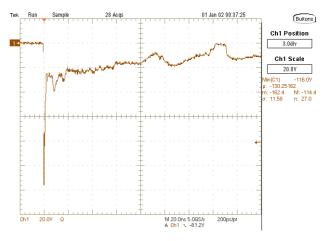
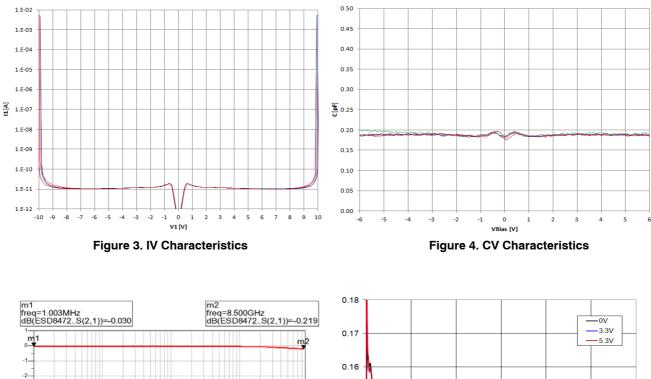
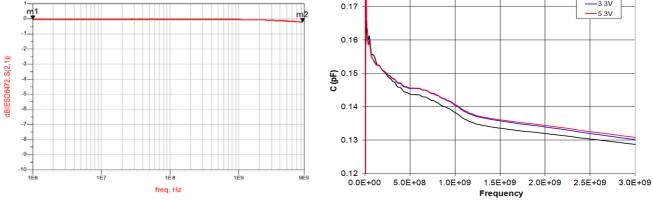


Figure 2. ESD Clamping Voltage Screenshot Negative 8 kV Contact per IEC61000-4-2

www.BD^{ht}P://Insemi.com

TYPICAL CHARACTERISTICS









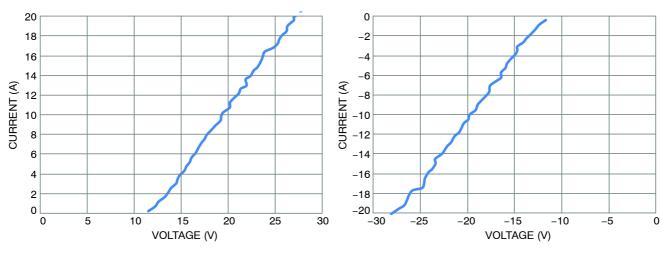


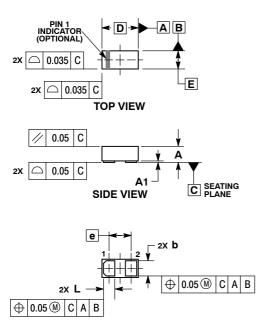


Figure 8. Negative TLP I–V Curve

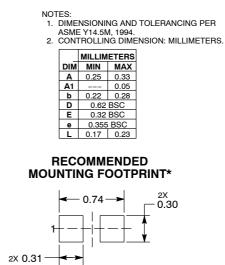
www.BDhtp://hemi.com.com/ON/

PACKAGE DIMENSIONS

X3DFN2, 0.62x0.32, 0.355P, (0201) CASE 152AF ISSUE O



BOTTOM VIEW



DIMENSIONS: MILLIMETERS

See Application Note AND8398/D for more mounting details

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and **ON** are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of SCILLC's product/patent coverage may be accessed at www.onsemic.com/site/pdf/Patent-Marking.pdf. SCILLC protects for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC products for any paricular purpose, nor other application is patent rights of others. SCILLC products are not designed, intended, or authorized for use as components insystems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, interctly, or indirectly, or indirectly, or other application with associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

www.BDTIC.com/ON/

Phone: 421 33 790 2910

Phone: 81-3-5817-1050

Japan Customer Focus Center